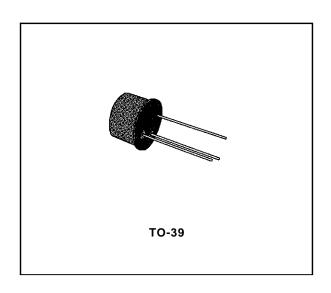
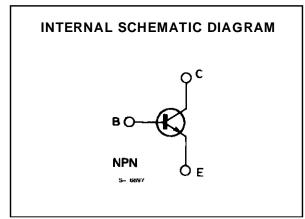
# BF257 BF258-BF259

### HIGH VOLTAGE VIDEO AMPLIFIERS

#### **DESCRIPTION**

The BF257, BF258 and BF259 are silicon planar epitaxial NPN transistors in Jedec TO-39 metal case. They are particularly designed for video output stages in CTV and MTV sets, class A audio output stages and drivers for horizontal deflection circuits.





#### **ABSOLUTE MAXIMUM RATINGS**

| Symbol           | Parameter   | Value       |       |       | Unit  |
|------------------|---|-------------|-------|-------|-------|
|                  | i diametei  |             | BF258 | BF259 | Oiiit |
| V <sub>CBO</sub> | Collector-base Voltage (I <sub>E</sub> = 0)         | 160         | 250   | 300   | V     |
| V <sub>CEO</sub> | Collector-emitter Voltage (I <sub>B</sub> = 0)      | 160         | 250   | 300   | V     |
| $V_{EBO}$        | Emitter-base Voltage (I <sub>C</sub> = 0)           | 5           |       |       | V     |
| Ic               | Collector Current                                   | 100         |       | mA    |       |
| I <sub>CM</sub>  | Collector Peak Current                              | 200         |       | mA    |       |
| $P_{tot}$        | Total Power Dissipation at T <sub>amb</sub> ≤ 50 °C | 5           |       | W     |       |
| T <sub>stg</sub> | Storage Temperature                                 | – 55 to 200 |       | °C    |       |
| Tj               | Junction Temperature                                | 200         |       | °C    |       |

October 1988 1/5

#### THERMAL DATA

| R <sub>th j-case</sub> | Thermal Resistance Junction-case    | Max | 30  | °C/W |
|------------------------|-------------------------------------|-----|-----|------|
| R <sub>th j-amb</sub>  | Thermal Resistance Junction-ambient | Max | 175 | °C/W |

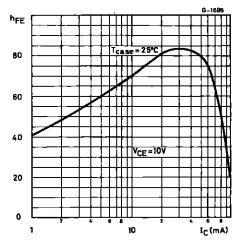
# **ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25 \, ^{\circ}C$ unless otherwise specified)

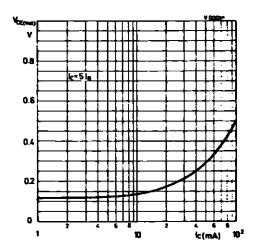
| Symbol                  | Parameter   | Test Conditions                     |  | Min.              | Тур. | Max.           | Unit           |
|-------------------------|---|-------------------------------------|--|-------------------|------|----------------|----------------|
| I <sub>CBO</sub>        | Collector Cutoff Current (I <sub>E</sub> = 0)               | for BF257<br>for BF258<br>for BF259 | $V_{CB} = 100 \text{ V}$<br>$V_{CB} = 200 \text{ V}$<br>$V_{CB} = 250 \text{ V}$ |                   |      | 50<br>50<br>50 | nA<br>nA<br>nA |
| V <sub>(BR)</sub> CBO   | Collector-base<br>Breakdown Voltage<br>(I <sub>E</sub> = 0) | I <sub>C</sub> = 100 μA             | for BF257<br>for BF258<br>for BF259  | 160<br>250<br>300 |      |                | V<br>V<br>V    |
| V <sub>(BR)CEO</sub> *  | Collector-emitter Breakdown Voltage (I <sub>B</sub> = 0)    | I <sub>C</sub> = 10 mA              | for <b>BF257</b><br>for <b>BF258</b><br>for <b>BF259</b>                         | 160<br>250<br>300 |      |                | V<br>V<br>V    |
| V <sub>(BR)</sub> EBO   | Emittter-base Breakdown Voltage (I <sub>C</sub> = 0)        | I <sub>E</sub> = 100 μA             |  | 5                 |      |                | V              |
| V <sub>CE (sat)</sub> * | Collector-emitter<br>Saturation Voltage                     | I <sub>C</sub> = 30 mA              | I <sub>B</sub> = 6 mA  |                   |      | 1              | V              |
| h <sub>FE</sub> *       | DC Current Gain   | I <sub>C</sub> = 30 mA              | V <sub>CE</sub> = 10 V   | 25                |      |                |                |
| f <sub>T</sub>          | Transition Frequency  | I <sub>C</sub> = 15 mA              | $V_{CE} = 10 \text{ V}$  |                   | 90   |                | MHz            |
| C <sub>re</sub>         | Reverse Capacitance   | I <sub>C</sub> = 0<br>f = 1 MHz     | V <sub>CE</sub> = 30 V   |                   | 3    |                | pF             |

<sup>\*</sup> Pulsed : pulse duration = 300  $\mu$ s, duty cycle = 1 %.

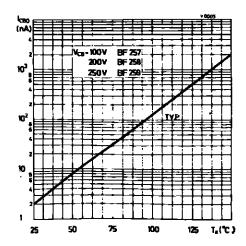
#### DC Current Gain.

2/5

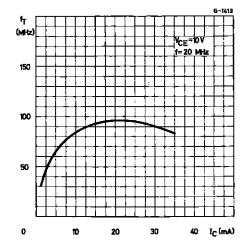




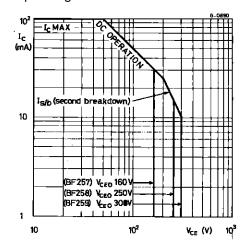
#### Collector Cutoff Current.



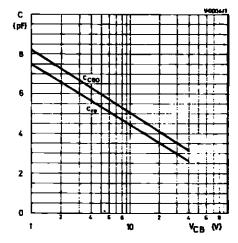
#### Transition Frequency.



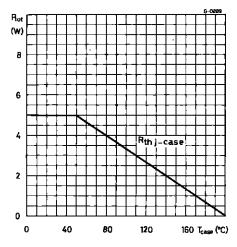
Safe Operating Area.



#### Collector-base Capacitance.

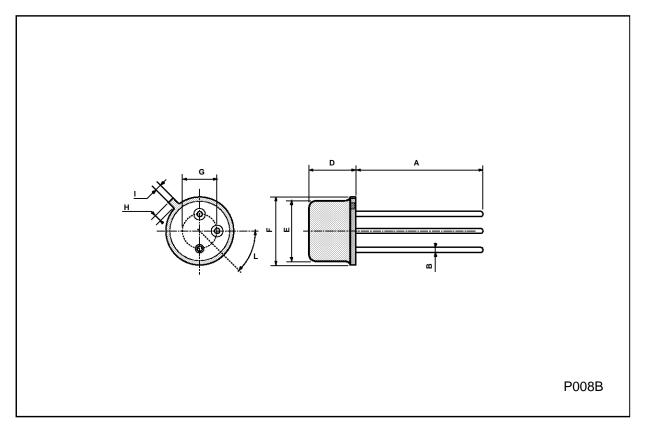


Power Rating Chart.



### **TO39 MECHANICAL DATA**

| DIM. | mm         |      |      | inch  |      |       |  |
|------|------------|------|------|-------|------|-------|--|
|      | MIN.       | TYP. | MAX. | MIN.  | TYP. | MAX.  |  |
| А    | 12.7       |      |      | 0.500 |      |       |  |
| В    |            |      | 0.49 |       |      | 0.019 |  |
| D    |            |      | 6.6  |       |      | 0.260 |  |
| E    |            |      | 8.5  |       |      | 0.334 |  |
| F    |            |      | 9.4  |       |      | 0.370 |  |
| G    | 5.08       |      |      | 0.200 |      |       |  |
| Н    |            |      | 1.2  |       |      | 0.047 |  |
| I    |            |      | 0.9  |       |      | 0.035 |  |
| L    | 45° (typ.) |      |      |       |      |       |  |



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